



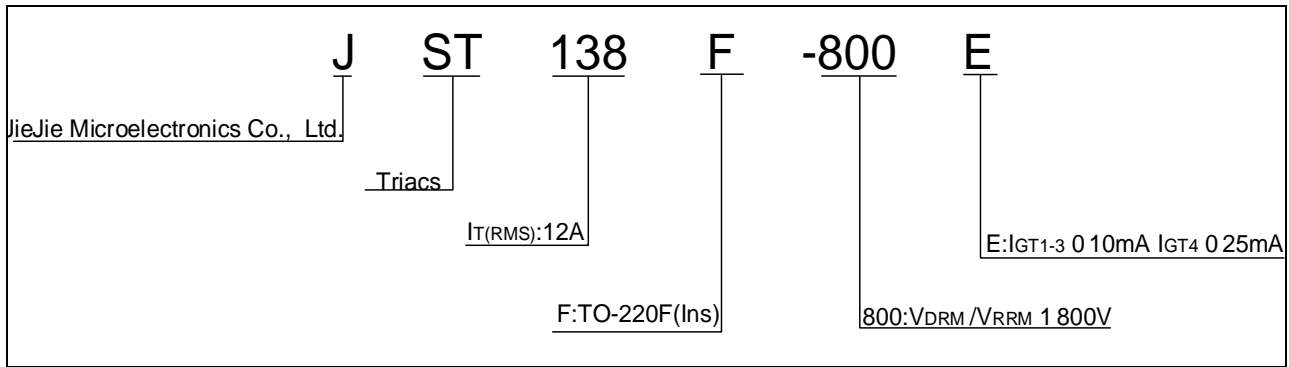
JST138F-800E 12A TRIAC

Rev.A.1.1

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JST138F-800E

\ R) ERING IN7 \ RMAT\ N



MARMING

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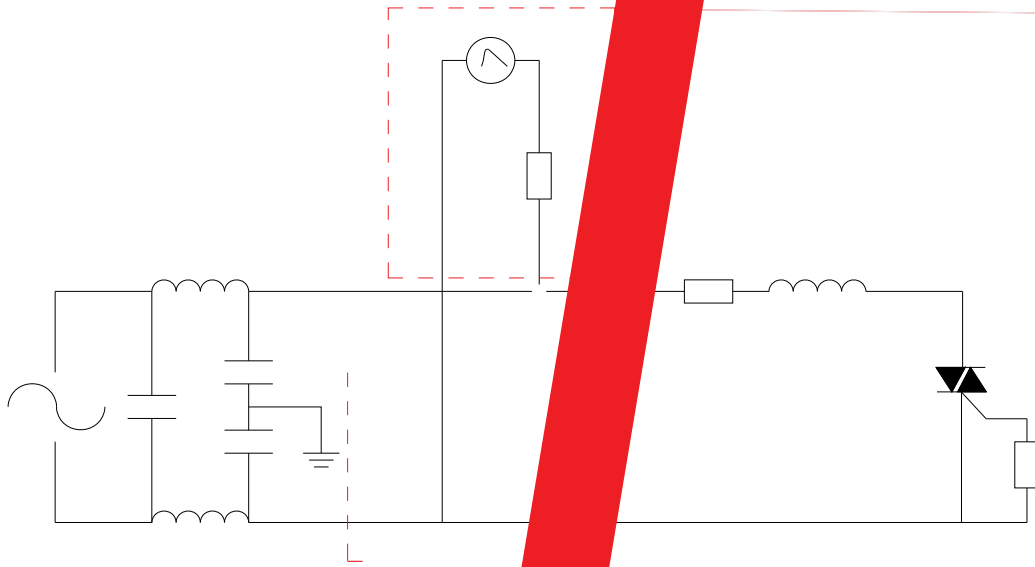
V V V _____

ST138F-800E

G.1: Maximum power dissipation versus P
n-state current



FIG.7 ÖTest circuit for inductive and resistive load to IEC-61000-4-5 standards



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| Order code | Voltage V _{DRM} /V _{RRM} (V) | IGT(mA) | | Package | Base qty. (pcs) | Delivery mode |
|--------------|---|---------|----|--------------|--------------------|---------------|
| | | - | - | | | |
| JST138F-800E | 800 | 10 | 25 | TO-220F(Ins) | 50 | Tube |

Document Revision History

| Date | Revision | Changes |
|--------------|----------|--------------------------------|
| Apr.14, 2023 | A.1.0 | Last updated |
| Oct.15, 2025 | A.1.1 | Revise PACKAGE MECHANICAL DATA |

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